

GTM ELECTRONICS

SOT-23 Switching Diodes

Part No.	Repetitive Peak Reverse Voltage	IO @TA = 25°C	IFSM Surge	Maximum Reverse Current @TA = 25°C		Maximum Forward Voltage @TA = 25°C		Cj pF	Marking Code
				IR uA	VR V	IFM mA	VFM V		
	V	mA	A						
GBAS16	85	250	1(1mS)	1	85	150	1.25	2	A6-
GBAV151	40	100	0.5(1S)	0.1	35	100	1.2	2	MA-
GBAV152	80	100	0.5(1S)	0.1	75	100	1.2	2	MB-
GBAV70	80	200	2(1uS)	5	80	100	1.3	1.5	A4-
GBAV99	70	150	1(1mS)	2.5	70	150	1.25	1.5	A7-
GBAW56	85	130	1(1mS)	1	80	150	1.25	2	A1-
GMBD1201	100	200	2(1mS)	0.05	50	300	1.4	2	D24
GMBD1201A	100	200	2(1mS)	0.05	50	300	1.4	2	D28
GMBD1201C	100	200	2(1mS)	0.05	50	300	1.4	2	D27
GMBD1201S	100	200	2(1mS)	0.05	50	300	1.4	2	D26
GMBD2004	300	225	4(1uS)	100	240	225	1.25	5	D53-
GMBD2004A	300	225	4(1uS)	100	240	225	1.25	5	DB8-
GMBD2004C	300	225	4(1uS)	100	240	225	1.25	5	DB7-
GMBD2004S	300	225	4(1uS)	100	240	225	1.25	5	DB6-
GMBD3004	350	225	4(1uS)	100	240	100	1	5	LD6
GMBD3004A	350	225	4(1uS)	100	240	100	1	5	LD7
GMBD3004C	350	225	4(1uS)	100	240	100	1	5	LD8
GMBD3004S	350	225	4(1uS)	100	240	100	1	5	LD9
GMBD4148	70	200	2(1uS)	5	75	10	1	4	5H-
GN202K	80	100	4(1uS)	0.1	70	100	1.2	3.5	A3
GP202K	80	100	4(1uS)	0.1	70	100	1.2	3.5	A2

量產	未量產	有樣品	工程實驗未產出
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